

PROCEEDINGS OF SPIE

Semiconductor Lasers and Applications VIII

Ning Hua Zhu
Werner H. Hofmann
Editors

12–13 October 2018
Beijing, China

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Published by
SPIE

Volume 10812

Proceedings of SPIE 0277-786X, V. 10812

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

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Please use the following format to cite material from these proceedings:

Author(s), "Title of Paper," in *Semiconductor Lasers and Applications VIII*, edited by Ning Hua Zhu, Werner H. Hofmann, Proceedings of SPIE Vol. 10812 (SPIE, Bellingham, WA, 2018) Seven-digit Article CID Number.

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510622227

ISBN: 9781510622234 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) Fax +1 360 647 1445

SPIE.org

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Printed in the United States of America

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